Preferred Device

Silicon Hot-Carrier Diodes

SCHOTTKY Barrier Diodes

These devices are designed primarily for high-efficiency UHF and VHF detector applications. They are readily adaptable to many other fast switching RF and digital applications. They are supplied in an inexpensive plastic package for low-cost, high-volume consumer and industrial/commercial requirements. They are also available in a Surface Mount package.

Features

- Extremely Low Minority Carrier Lifetime 15 ps (Typ)
- Very Low Capacitance -1.5 pF (Max) @ $V_R = 15 \text{ V}$
- Low Reverse Leakage I_R = 13 nAdc (Typ) MBD301, MMBD301
- Pb-Free Packages are Available

MAXIMUM RATINGS

		MBD301	MMBD301LT1	
Rating	Symbol	,	Unit	
Reverse Voltage	V _R	30		V
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _F	280 2.8	200 2.0	mW mW/°C
Operating Junction Temperature Range	TJ	-55 to +125		°C
Storage Temperature Range	T _{stg}	-55 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

http://onsemi.com

30 VOLTS SILICON HOT-CARRIER DETECTOR AND SWITCHING DIODES

MBD301

MARKING DIAGRAM



TO-92 (TO-226AC) CASE 182 STYLE 1





MMBD301LT1

MARKING DIAGRAM



SOT-23 (TO-236) CASE 318 STYLE 8



M = Date Code■ Pb-Free Package

(Note: Microdot may be in either location)



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μA)	$V_{(BR)R}$	30	_	_	V
Total Capacitance (V _R = 15 V, f = 1.0 MHz) Figure 1	C _T	_	0.9	1.5	pF
Reverse Leakage (V _R = 25 V) Figure 3	I _R	_	13	200	nAdc
Forward Voltage (I _F = 1.0 mAdc) Figure 4	V _F	_	0.38	0.45	Vdc
Forward Voltage (I _F = 10 mAdc) Figure 4	V _F	_	0.52	0.6	Vdc

ORDERING INFORMATION

Device	Package	Shipping [†]		
MBD301	TO-92	5000 Units / Bulk		
MBD301G	TO-92 (Pb-Free)	5000 Units / Bulk		
MMBD301LT1	SOT-23	3000 / Tape & Reel		
MMBD301LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel		
MMBD301LT3	SOT-23	10,000 / Tape & Reel		
MMBD301LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL ELECTRICAL CHARACTERISTICS

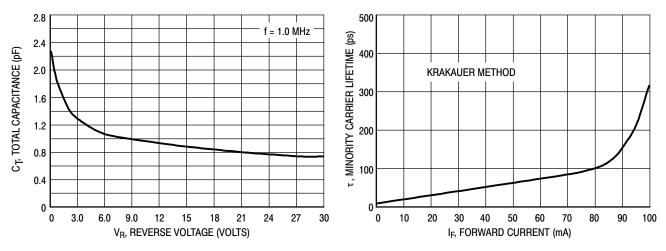


Figure 1. Total Capacitance

Figure 2. Minority Carrier Lifetime

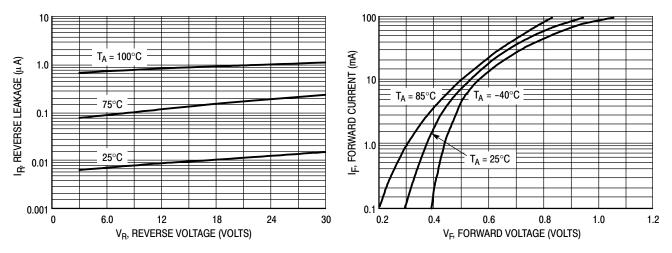


Figure 3. Reverse Leakage

Figure 4. Forward Voltage

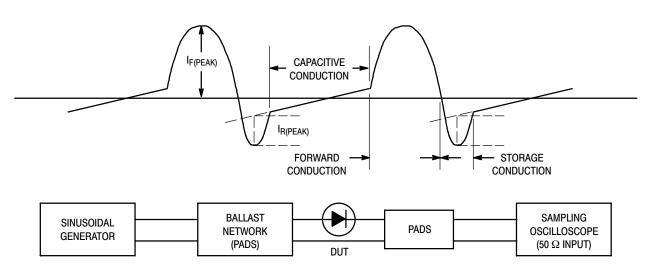
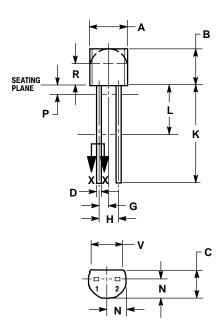


Figure 5. Krakauer Method of Measuring Lifetime

PACKAGE DIMENSIONS

TO-92 (TO-226AC) CASE 182-06 ISSUE L





SECTION X-X

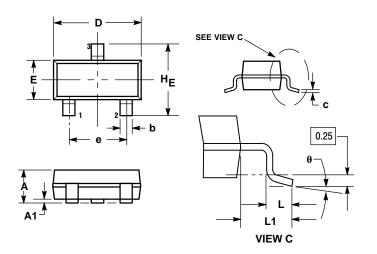
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND ZONE R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.21	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.050 BSC		1.27 BSC		
Н	0.100 BSC		2.54 BSC		
J	0.014	0.016	0.36	0.41	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.03	2.66	
P		0.050		1.27	
R	0.115		2.93		
٧	0.135		3.43		

STYLE 1: PIN 1. ANODE 2. CATHODE

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**



NOTES

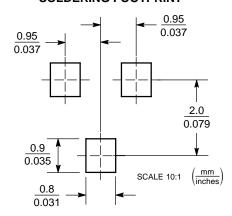
- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982
- CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 8:

- PIN 1. ANODE
 - NO CONNECTION
 - CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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